

Contents

Foreword *IX*
List of Contributors *XI*

Introduction *1*

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References *5*

1	Quantum Dot Technologies <i>7</i>
	<i>Richard A. Hogg and Ziyang Zhang</i>
1.1	Motivation for Development of Quantum Dots <i>7</i>
1.2	Gain and Quantum Confinement in a Semiconductor Laser <i>7</i>
1.2.1	Top-Down Approach <i>10</i>
1.2.2	Bottom-Up Approach <i>13</i>
1.3	Self-Assembled Quantum Dot Technology <i>14</i>
1.3.1	Molecular Beam Epitaxy <i>14</i>
1.3.2	Growth Modes <i>17</i>
1.3.3	Quantum Dot Growth Dynamics <i>18</i>
1.3.3.1	The Interaction of the Quantum Dot and the Wetting Layer <i>18</i>
1.3.3.2	The Interaction of the Quantum Dot with Underlying Layers and Capping Layers <i>19</i>
1.3.3.3	Growth Interruption <i>19</i>
1.3.3.4	Arsenic Pressure <i>20</i>
1.3.3.5	Growth Temperature <i>20</i>
1.3.3.6	Growth Rate and Material Coverage <i>21</i>
1.3.4	Quantum Dot Growth Thermodynamic Processes <i>21</i>
1.4	Physics and Device Properties of S-K Quantum Dots <i>23</i>
1.4.1	Temperature Insensitivity <i>23</i>
1.4.2	Low Threshold Current Density <i>24</i>
1.4.3	Material Gain and Modal Gain <i>25</i>
1.4.4	Broad Spectral Bandwidth Devices and Spectral Coverage <i>25</i>
1.4.5	Ultrafast Gain Recovery <i>29</i>

1.5	Extension of Emission Wavelength of GaAs-Based Quantum Dots	31
1.5.1	Short-Wavelength Quantum Dot Light Emission	31
1.5.1.1	InP/GaInP Quantum Dots	31
1.5.1.2	Type II InAlAs/AlGaAs Quantum Dots	33
1.5.2	Long-Wavelength QD Light Emission	33
1.5.2.1	Low Growth Temperature InAs/GaAs Quantum Dots	34
1.5.2.2	InAs QDs Grown on an InGaAs Metamorphic Layer	34
1.5.2.3	InGaAsSb Capped InAs/GaAs Quantum Dots and InGaNAs Capped InAs/GaAs Quantum Dots	34
1.5.2.4	Bilayer InAs/GaAs QD Structures	34
1.5.2.5	Asymmetric Dot in WELL QD Structure	34
1.6	Future Prospects	36
	Acknowledgments	37
	References	37
2	Ultra-Short-Pulse QD Edge-Emitting Lasers	43
	<i>Stefan Breuer, Dimitris Syrigidis, and Edik U. Rafailov</i>	
2.1	Introduction	43
2.2	Simulations	45
2.3	Broadly Tunable Frequency-Doubled EC-QD Lasers	48
2.4	Two-Section Monolithic Mode-Locked QD Lasers	52
2.4.1	Simultaneous GS and ES ML	53
2.4.2	QD Absorber Resistor-SEED Functionality	57
2.4.3	Pulse Width Narrowing due to GS Splitting	59
2.5	Tapered Monolithic Mode-Locked QD Lasers	61
2.5.1	High-Peak Power and Subpicosecond Pulse Generation	62
2.5.2	Suppression of Pulse Train Instabilities of Tapered QD-MLLs	69
2.6	QD-SOAs	71
2.6.1	Straight-Waveguide QD-SOAs	71
2.6.2	Tapered-Waveguide QD-SOAs	72
2.6.3	QD-SOA Noise	75
2.7	Pulsed EC-QD Lasers with Tapered QD-SOA	77
2.7.1	EC-MLQDL	77
2.7.2	EC-MLQDL with Postamplification by Tapered QD-SOA	80
2.7.3	Wavelength-Tunable EC-MLQDL with Tapered QD-SOA	84
2.8	Conclusion	87
	Acknowledgments	88
	References	89
3	Quantum Dot Semiconductor Disk Lasers	95
	<i>Jussi Rautianen, Mantas Butkus, and Oleg Okhotnikov</i>	
3.1	Introduction	95
3.2	General Concept of Semiconductor Disk Lasers	96
3.3	Toward Operation at the 1–1.3 μm Spectral Range	98
3.4	Quantum Dots Growth and Characterization	98

3.5	Quantum Dots for Laser Application: From Edge Emitters to Disk Lasers	99
3.6	Details of the Quantum Dot Gain Media for Disk Cavity	99
3.6.1	1040 nm Disk Gain Design	101
3.6.2	1180 nm Disk Gain Structure	101
3.6.3	1260 nm Disk Gain Structure	101
3.6.4	Gain Medium Characterization at the Wafer Level	103
3.7	Disk Laser Performance	107
3.7.1	Gain Chip Assembly and Thermal Management	107
3.7.2	1040 nm InGaAs Dot Disk Laser	107
3.7.3	1180 nm Disk Laser	108
3.7.4	1260 nm Quantum Dot Disk Laser	109
3.8	Tunable Quantum Dot Semiconductor Disk Laser	111
3.9	Second Harmonic Generation with Quantum Dot Disk Laser Cavity	111
3.9.1	Experimental Results	113
3.10	Disk Laser with Flip-Chip Design of the Gain Medium	114
3.10.1	Gain Structure Description	115
3.10.2	Experimental Results	115
3.11	Conclusions	116
	Acknowledgments	116
	References	116
4	Semiconductor Quantum-Dot Saturable Absorber Mirrors for Mode-Locking Solid-State Lasers	121
	<i>Valdas Pasiskevicius, Niels Meiser, Mantas Butkus, Bojan Resan, Kurt J. Weingarten, Richard A. Hogg, and Ziyang Zhang</i>	
4.1	Scope of the Chapter	121
4.2	Introduction	122
4.3	Quantum-Well Saturable Absorbers: Overview	123
4.4	Quantum-Dot Saturable Absorbers: Basic Principles and Fabrication Technologies	126
4.5	Quantum-Dot Saturable Absorbers for Mode-Locking of Solid-State Lasers at 1 μm	132
4.5.1	QD-SAM Design and Characterization	132
4.5.2	QD-SAM Mode-Locked Yb:KYW Lasers	140
4.6	p-i-n Junction QD SESAMs and Their Applications	143
4.6.1	Cr:forsterite Laser Mode-Locked Using p-i-n QD SESAM	145
4.6.2	Nonlinear Reflectivity and Absorption Recovery Dynamics in p-i-n QD-SAM	147
4.7	InAs/GaAs QD-SAM for 10 GHz Repetition Rate Mode-Locked Laser at 1.55 μm	151
4.8	InP Quantum Dot Saturable Absorbers for Mode-Locking High-Repetition Rate Ti:sapphire Lasers	157
4.9	Conclusions	160

	Acknowledgments	160
	References	160
5	QD Ultrafast and Continuous Wavelength Laser Diodes for Applications in Biology and Medicine	171
	<i>Pablo Loza-Alvarez, Rodrigo Avilés-Espinosa, Steve J. Matcher, D. Childs, and Sergei G. Sokolovski</i>	
5.1	Compact Laser Systems for Nonlinear Imaging Applications	171
5.1.1	Introduction	171
5.1.1.1	The Multimodal Microscope	174
5.1.2	Microscopy Workstation Preparation for Infrared Wavelengths	176
5.1.2.1	Long-Term Exposure Effects on Living Samples at 1550 nm	178
5.1.3	Quantum-Dot-Based Optically Pumped Vertical Extended Cavity Surface-Emitting Lasers for Nonlinear Imaging	181
5.1.3.1	The Compact Femtosecond Semiconductor Disk Laser System	181
5.1.3.2	Nonlinear Imaging Tests	182
5.1.4	Future Prospects: Edge-Emitting Laser Prototypes for Nonlinear Imaging	188
5.1.4.1	Ultra-Short Pulsed Semiconductor Edge-Emitting Lasers	188
5.1.5	Conclusions	194
5.2	QD Devices and Their Application in Optical Coherence Tomography	196
5.2.1	Overview of Optical Coherence Tomography	196
5.2.2	SLD Devices	199
5.2.3	Broadband Gain Material	202
5.2.3.1	Use of QDs SLDs for Time-Domain OCT	204
5.2.4	Swept Lasers	206
5.2.5	The QD Swept Source Laser for OCT	209
5.2.6	Summary and Future Outlook	212
5.3	Infrared QD Laser Application in Cancer Photodynamic Therapy: Killing Tumor Cells without Photosensitizers	212
5.3.1	Introduction	213
5.3.2	Singlet Oxygen in Organic Solution	214
5.3.3	Laser-Induced $^1\text{O}_2$ Production in Living Cells	216
5.3.4	Cytosolic Free Calcium Level and Ion Channel Activity under Laser Pulse	218
5.3.5	Laser-Triggered Cancer Cell Death	220
5.3.6	Conclusions and Future Perspectives	221
	Acknowledgments	222
	References	222
6	Conclusion and Future Perspectives	231
	<i>Edik U. Rafailov</i>	
	Color Plates	233
	Index	249